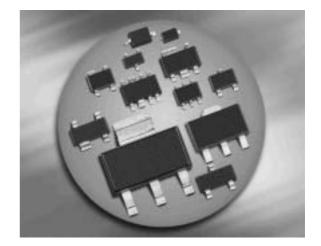


Silicon Switching Diode

- For high-speed switching applications
- Series pair configuration
- BAV99S / U: For orientation in reel see package information below
- Pb-free (RoHS compliant) package¹⁾
- Qualified according AEC Q101







BAV99 BAV99W

BAV99S BAV99U





Туре	Package	Configuration	Marking
BAV99	SOT23	series	A7s
BAV99S	SOT363	dual series	A7s
BAV99U	SC74	dual series	A7s
BAV99W	SOT323	series	A7s

1

2007-09-19

¹Pb-containing package may be available upon special request



Maximum Ratings at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_{R}	80	V
Peak reverse voltage	V_{RM}	85	
Forward current	I _F	200	mA
Non-repetitive peak surge forward current	I _{FSM}		Α
$t = 1 \mu s$		4.5	
t = 1 ms		1	
t = 1 s, single		0.5	
t = 1 s, double		0.75	
Total power dissipation	P _{tot}		mW
BAV99, <i>T</i> _S ≤ 28°C		330	
BAV99S, <i>T</i> _S ≤ 85°C		250	
BAV99U, <i>T</i> _S ≤ 113°C		250	
BAV99W, <i>T</i> _S ≤ 110°C		250	
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-65 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R _{thJS}		K/W
BAV99		≤ 360	
BAV99S		≤ 260	
BAV99U		≤ 150	
BAV99W		≤ 160	

 $^{^{1}\}mathrm{For}$ calculation of R_{thJA} please refer to Application Note Thermal Resistance



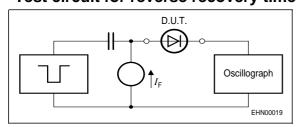
Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage	$V_{(BR)}$	85	-	-	V
$I_{(BR)} = 100 \ \mu A$					
Reverse current	I_{R}				μΑ
<i>V</i> _R = 70 V		-	-	0.15	
$V_{R} = 25 \text{ V}, T_{A} = 150 ^{\circ}\text{C}$		-	-	30	
$V_{R} = 70 \text{ V}, T_{A} = 150 ^{\circ}\text{C}$		-	-	50	
Forward voltage	V_{F}				mV
$I_{F} = 1 \; mA$		-	-	715	
$I_{\rm F} = 10 \; {\rm mA}$		-	-	855	
$I_{\rm F} = 50 \; {\rm mA}$		-	_	1000	
$I_{\rm F} = 100 {\rm mA}$		-	-	1200	
$I_{\rm F}$ = 150 mA		_	-	1250	

Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
AC Characteristics					
Diode capacitance	C _T	-	-	1.5	pF
$V_{R} = 0 \text{ V}, f = 1 \text{ MHz}$					
Reverse recovery time	<i>t</i> _{rr}	-	-	4	ns
$I_{\rm F}$ = 10 mA, $I_{\rm R}$ = 10 mA, measured at $I_{\rm R}$ = 1mA,					
R_{L} = 100 Ω					

Test circuit for reverse recovery time



Pulse generator: $t_p = 100$ ns, D = 0.05,

$$t_{\rm r}$$
 = 0.6ns, $R_{\rm i}$ = 50 Ω

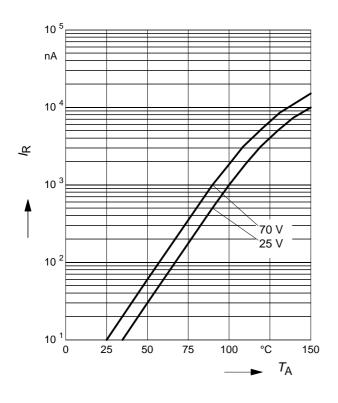
Oscillograph: R = 50, $t_{\rm f} = 0.35$ ns

3 2007-09-19



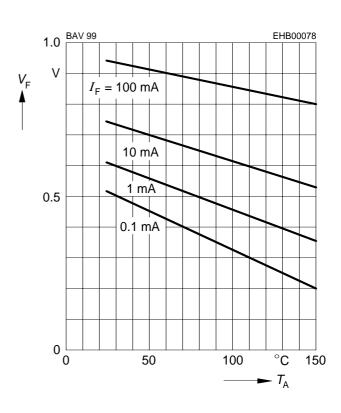
Reverse current $I_R = f(T_A)$

 V_{R} = Parameter



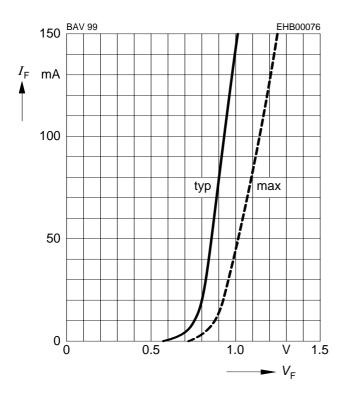
Forward Voltage $V_F = f(T_A)$

 I_{F} = Parameter



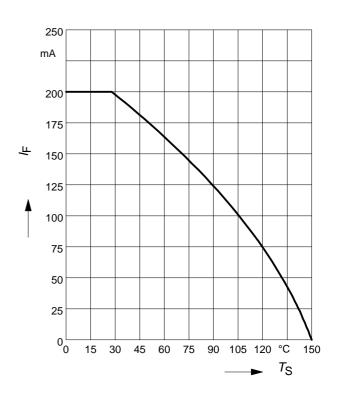
Forward current $I_F = f(V_F)$

 $T_A = 25^{\circ}C$



Forward current $I_F = f(T_S)$

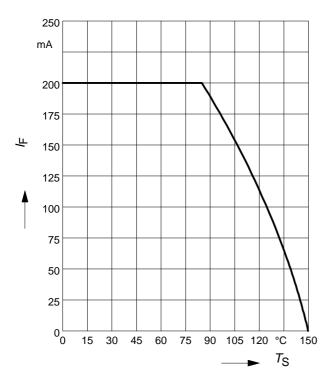
BAV99





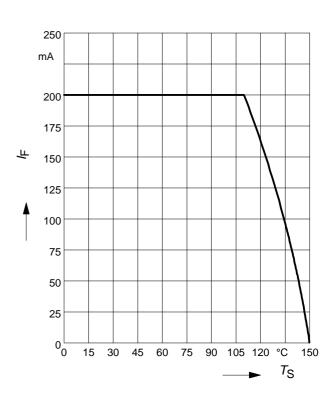
Forward current $I_F = f(T_S)$

BAV99S



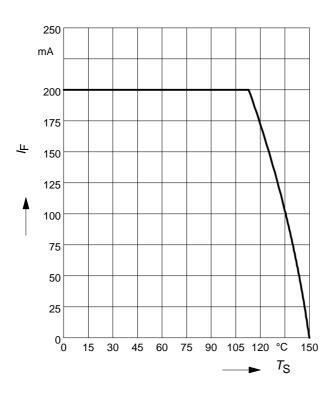
Forward current $I_F = f(T_S)$

BAV99U



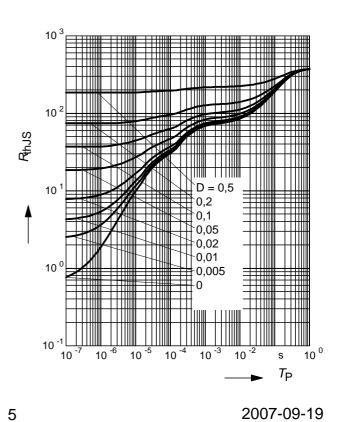
Forward current $I_F = f(T_S)$

BAV99W



Permissible Puls Load $R_{thJS} = f(t_p)$

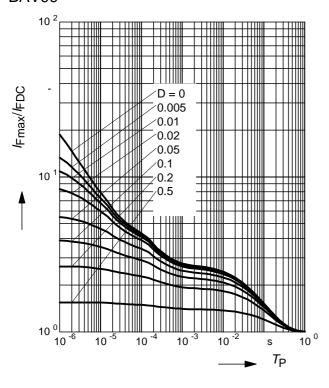
BAV99





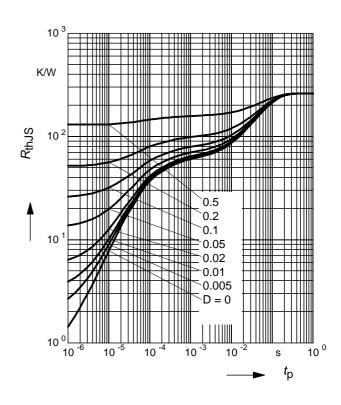
Permissible Pulse Load

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV99



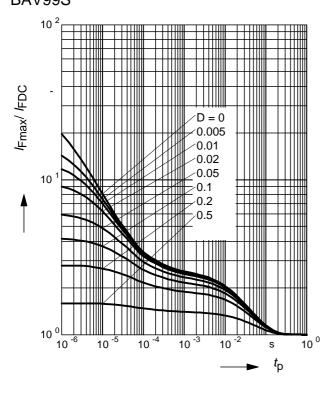
Permissible Puls Load $R_{thJS} = f(t_p)$

BAV99S



Permissible Pulse Load

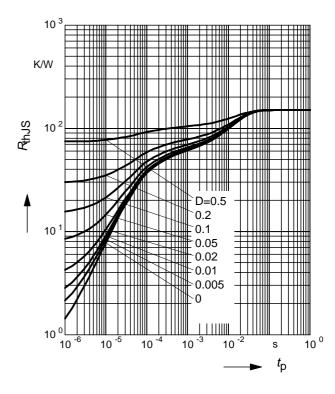
 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV99S



Permissible Puls Load $R_{thJS} = f(t_p)$

BAV99U

6

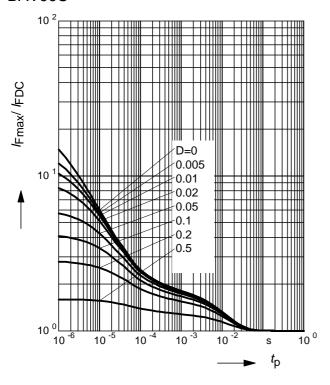


2007-09-19



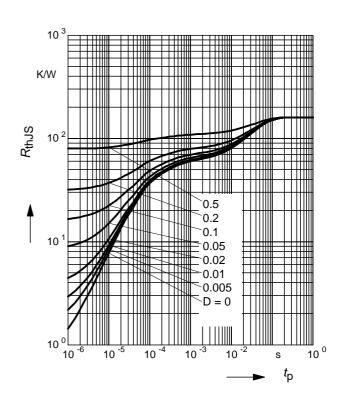
Permissible Pulse Load

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV99U



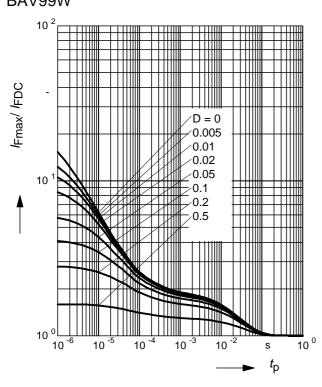
Permissible Puls Load $R_{thJS} = f(t_p)$

BAV99W



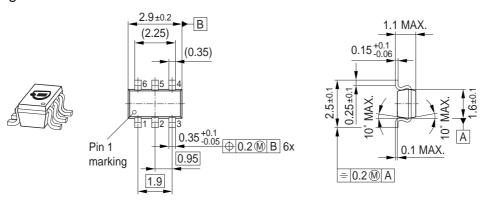
Permissible Pulse Load

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV99W

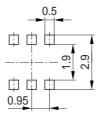


7 2007-09-19



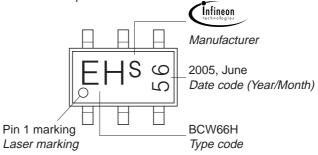


Foot Print



Marking Layout (Example)

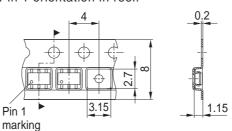
Small variations in positioning of Date code, Type code and Manufacture are possible.



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

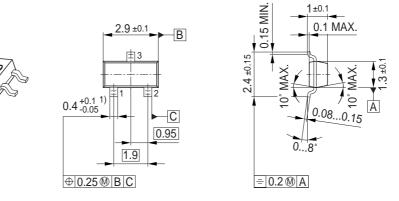
For symmetric types no defined Pin 1 orientation in reel.



8

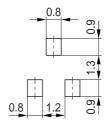
2007-09-19



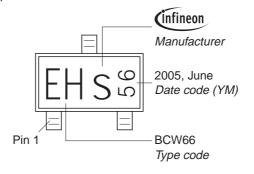


1) Lead width can be 0.6 max. in dambar area

Foot Print

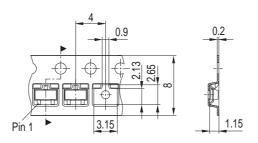


Marking Layout (Example)



Standard Packing

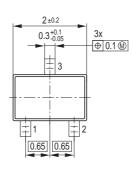
Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

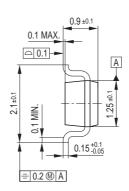


9

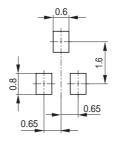




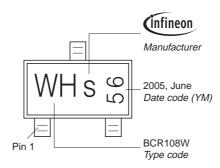




Foot Print

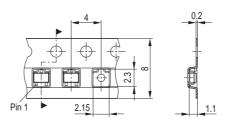


Marking Layout (Example)



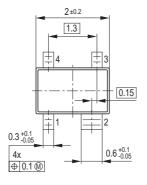
Standard Packing

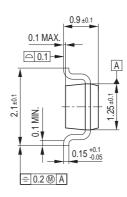
Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



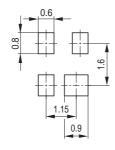




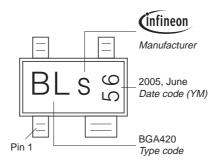




Foot Print

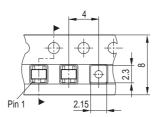


Marking Layout (Example)



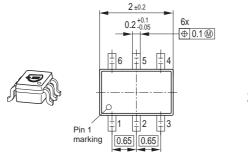
Standard Packing

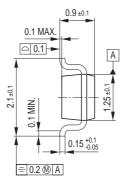
Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



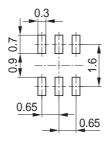






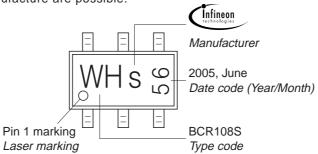


Foot Print



Marking Layout (Example)

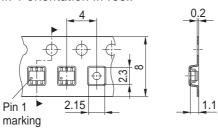
Small variations in positioning of Date code, Type code and Manufacture are possible.



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.





Edition 2006-02-01 Published by Infineon Technologies AG 81726 München, Germany © Infineon Technologies AG 2007. All Rights Reserved.

Attention please!

The information given in this dokument shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie"). With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system.

Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

13 2007-09-19